



### **PHYSICS**

# BOOKS - NN GHOSH PHYSICS (HINGLISH)

## **DIODE, TRIODE & TRANSISTER**

#### Examples

**1.** In a diode valve the space-charge limited current at 100 V is 100 mA. What is the space-

charge current at 150 V?



**2.** In a diode valve the saturation current at 750 K is 100 mA. What is the saturation current at 800 K ? Work function of metal is 1.6 eV.



**3.** The equation of the working part of the characteristic of a diode can be written as  $I = 0.75 \times 10^{-3}V - 2 \times 10^{-3}A$ . Calculate the load current, voltage and power dissipated at the plate when a load of resistance  $1000\Omega$  and 100V from a source are applied.

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**4.** In the normal operating region, the characteristics of a certain triode may be

written as

 $I_p = 10^{-5}(160V_S + 2.22V_p)$ 

Determine analytically the values of

 $\mu, r_p \text{ and } g_m.$ 

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5. The current conducted by the p-n junction of a semiconductor diode is  $100\mu A$  at a voltage of -1V. Calculate the current at a voltage of +0.2V. 6. Calculate the electrical resistivity and conductivity of a silicon crystal if every 10 mollion silicon atoms is replaced by an atom of indium. Given that intrinsic carrier density of silicon  $= 1.5 imes 10^{16} m^{-3}$ , atomic weight of silicon = 28.09, density of silicon  $=2330 {
m kg} {
m m}^{-3}$ , mobility of electrons  $(\mu_n)=0.135$ , that of holes  $(\mu_p)=0.018$ , By how many times is the conductivity increased

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?

#### Exercises

**1.** A diode has Child's constant K = 0.2(current in mA and voltage in volts). Calculate the voltage across the tube, across a load of resistance  $10000\Omega$  and source the voltage when the tube produces a current of 12.8 mA through the load.

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2. In a certain triode, the output is 5 mA with an anode potential of 200 V and grid potential -3V. When he potential is increased to 260 V, the current rises 10.7mA. A charge in grid voltage to -4V restores the current to the original value. Find the constant of the valve

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**3.** A triode value of anode slope resistance  $20k\Omega$  is used with an anode load resistance of  $50k\Omega$ . If an alternating signal of 0.5 V (rms

value) is applied to the grid, find the output if

the amplification factor of the valve is 15.



**4.** The voltage of a triode amplifier with a resistive load of  $5k\Omega$  is 10 while with a resistive load of  $12k\Omega$ . It is 15. Calculate the amplification factor and plate resistance of the triode.



5. The plate resistance of a triode is  $7.7k\Omega$ , and the transconductanace is 2.6 millimho. If only the plate voltage is increased by 50 V, what is the increase in the plate current ? What change in grid voltage will now bring the plate current to its former value ?



6. Determine the conductivity of pure germanium at  $27^{\circ}C$ . The concentration of the carriers at this temperature is  $2.2 imes 10^{19}m^{-3}$ .

The mobility of electrons = 0.36 and that of

holes = 0.17



7. In a p-n junction diode the reverse saturation current is  $10\mu A$ . What will be the forward current for a voltager of 0.2 V ?

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**8.** Assume that the silicon diode in the given circuit requires a minimum current of 1 mA to be above the (knee-point voltage = 0.7 V) of its I-V characteristics. Assuming that the voltage across the diode is independent of current above the knee-point, find the maximum value of R so that the voltage is above the knee-point if  $V_B = 5A$ . Also find the value of R to establish a current of 5 mA in the

#### circuit for the since voltage.



**9.** The base current of a transistor is  $105\mu A$ and the collector current is 2.05 mA. Determine the alue of  $\beta$ ,  $I_C$  and  $\alpha$ . If a change of  $27\mu A$  in the base current produces

a change of 0.65 mA in the collector, find  $\beta_{ac}$ .



**10.** In a silicon transistor, a change of 7.89 mA in the emitter current produces a change of 7.89 mA in the collector current. What change in the base current will bring the same change in the collector current ?



**11.** In a silicon transistor the base current is changed by  $20\mu A$ . This results in a change of 0.02 V in the base to emitter voltage and a changed of 2 mA in the collector current (a) Find the input resistance  $r_b, \beta_{ac}$  and transconductance  $g_m$  of the transistor (b) The transistor is used as an amplifier with a load resistance of  $5k\Omega$ . What is the voltage gain of the amplifier ?

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**12.** In triode valve, for a grid voltage  $V_q = -1.2V$ , the plate current  $I_p$  (in mA) ad the plate voltage are given by the relation  $I_p = -50 + 0.1 V_p$ , when the grid voltage is changed to -3.2V and the plate voltage is kept at 150 V, plate current of 5 mA is observed. Calculate the valve constant and the voltage amplification for  $20k\Omega$  load in the plate circuit.



**13.** In the accompanying circuit (Fig. 5.9) the value of  $\beta$  is 100. Find  $I_B$ ,  $V_{CE}$ ,  $V_{CE}$  and  $V_{BC}$ , when  $I_C = 1.5mA$ . Is the transistor in active, cut-off or saturation state ?





14. In the accompanying circuit Fig. 5.10, if it is assumed that when that input voltage at the base resistance is 5 V,  $V_{BE}$  is zero and  $V_{CE}$  is

also zero, what are  $I_B$ ,  $I_C$  and  $\beta$ ? When the input is zero,  $I_B$  is zero. What will be the output waveform if the input waveform is as shown in the figure ? What is the practial use of this current ?



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**15.** In the given circuit Fig. 5.11, the base current is  $10\mu A$  and the collector current is 52 mA. Can this transistor be used as an amplifier

?



**16.** In the given circuit (Fig. 5.12) calculate the value of the collector current if its  $I_{CD} = 10 \mu A$  and  $\alpha = 0.97$ . Assume a voltage drop between base and emitter of 0.15 V







#### 17. Calculate the emiter current and collector

#### voltage of the circuit given in Fig. 5.13



**18.** A transistor connected in common emitter configuration has  $V_{CC} = 8V, V_L = 0.5V$  and  $R_L = 800\Omega$ . If its  $\alpha = 0.96$  determine (i) collector emitter voltage, (ii) its base current. Watch Video Solution

19. In a transistor collector load is  $4k\Omega$ whereas the zero signal current is 1 mA. (a) What is the operating point if  $V_{CC} = 10V$  ? (b) What will be the operating point if  $R_L=5k\Omega$  ?

[Hint : Operating point is zero signal collectorm current and  $V_{CO}$ ]